

## DC - 30 GHz Wideband Analog Attenuator



### Key Features

- Frequency Range: DC to 30 GHz
- 17 dB Variable Attenuation Range
- Insertion Loss: 1.5 dB Typical
- Input P1dB: >20 dBm Typical @ 10 dB Attenuation
- IM3: -40 dBc Typical @ Pin/Tone = 6dBm,
- Return Loss: 15 dB Typical
- Bias: -1V to 0 V
- Technology: 3MI 0.25 um mmw pHEMT
- Compact 3x3 QFN with 16 Leads
- Package Dimensions: 3 x 3 x 0.9 mm

### Primary Applications

- Point-to-Point Radio
- Fiber Optic
- Wideband Military & Space

### Product Description

The TriQuint TGL4203-SM is a wideband packaged Analog Attenuator. The TGL4203-SM operates from DC - 30 GHz and is designed using TriQuint's proven standard 0.25 um mmw pHEMT production process.

The TGL4203-SM typically provides 1.5 dB Insertion Loss, 17 dB variable Attenuation Range, >20 dBm Input Power @ 1dB compression Gain, -40 dBc IM3 @ 6 dBm Pin/Tone, with bias voltages from -1V to 0V.

The TGL4203-SM is available in a low-cost, compact surface mount 3x3 QFN style package with 16 leads. The wideband capabilities of this device are versatile in many applications such as Point to Point Radio, Fiber Optic, and Wideband Military & Space.

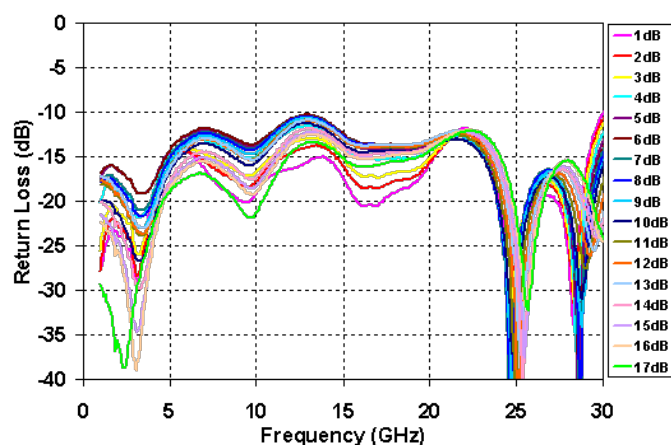
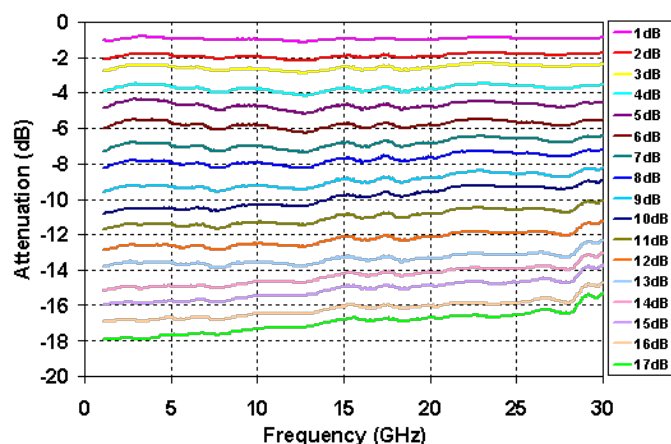
Evaluation Boards are available upon request.

Lead-free and RoHS compliant.

*Datasheet subject to change without notice.*

### Measured Performance

Bias conditions: -1V to 0V



**Table I**  
**Absolute Maximum Ratings 1/**

| Symbol   | Parameter                         | Value         | Notes |
|----------|-----------------------------------|---------------|-------|
| V1, V2   | Attenuation Control Voltage Range | -5 to +1 V    |       |
| I1       | V1 Supply Current                 | -1 to +8.8 mA |       |
| I2       | V2 Supply Current                 | -3 to +80 mA  |       |
| Pin      | Input Continuous Wave Power       | 24 dBm        |       |
| Tchannel | Channel Temperature               | 200 °C        |       |

1/ These ratings represent the maximum operable values for this device. Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device and / or affect device lifetime. These are stress ratings only, and functional operation of the device at these conditions is not implied.

**Table II**  
**Recommended Operating Conditions**

| Attenuation | V1 (V) | V2 (V) |
|-------------|--------|--------|
| REF         | 0.000  | -1.000 |
| 1dB         | -0.500 | -0.877 |
| 2dB         | -0.651 | -0.840 |
| 3dB         | -0.685 | -0.817 |
| 4dB         | -0.718 | -0.784 |
| 5dB         | -0.734 | -0.752 |
| 6dB         | -0.767 | -0.725 |
| 7dB         | -0.800 | -0.703 |
| 8dB         | -0.822 | -0.681 |
| 9dB         | -0.843 | -0.648 |
| 10dB        | -0.869 | -0.623 |
| 11dB        | -0.871 | -0.577 |
| 12dB        | -0.881 | -0.518 |
| 13dB        | -0.888 | -0.447 |
| 14dB        | -0.920 | -0.387 |
| 15dB        | -0.936 | -0.311 |
| 16dB        | -0.952 | -0.147 |
| 17dB        | -1.000 | 0.000  |

Bias Voltages Optimized for flatness of Attenuation with respect to reference over frequency

**Table III**  
**RF Characterization Table**

**Bias: -1 V to 0 V, (T<sub>A</sub> = 25 °C Nominal)**

| SYMBOL | PARAMETER   | TEST CONDITIONS             | MIN      | NOM      | MAX      | UNITS |
|--------|---|-----------------------------|----------|----------|----------|-------|
|        | Attenuation Range                                 | DC to 20 GHz<br>20 – 30 GHz | 13<br>10 | 16<br>15 | 19<br>20 | dB    |
| IL     | Insertion Loss                                    | DC to 20 GHz<br>20 – 30 GHz |          | 2<br>3.5 | 3<br>4.5 | dB    |
| IP1dB  | Input Power @ 1dB Gain compression @ 10 dB Atten. | 5 to 30 GHz                 |          | 20       |          | dBm   |
| IM3    | 3rd Harmonic Intermodulation @ Pin/Tone = 6dBm    | 5 to 30 GHz                 |          | -40      |          | dBc   |
| IRL    | Input Return Loss                                 | DC to 30 GHz                |          | 15       |          | dB    |
| ORL    | Output Return Loss                                | DC to 30 GHz                |          | 15       |          | dB    |
|        | Group Delay Variation                             | DC to 30 GHz                |          | +/-5     |          | psec  |
|        | Max. Insertion Loss Ripple                        | DC to 30 GHz                |          | 0.5      |          | dB    |
|        | Insertion Loss Temperature Coefficient            | DC to 30 GHz                |          | -0.01    |          | dB/°C |

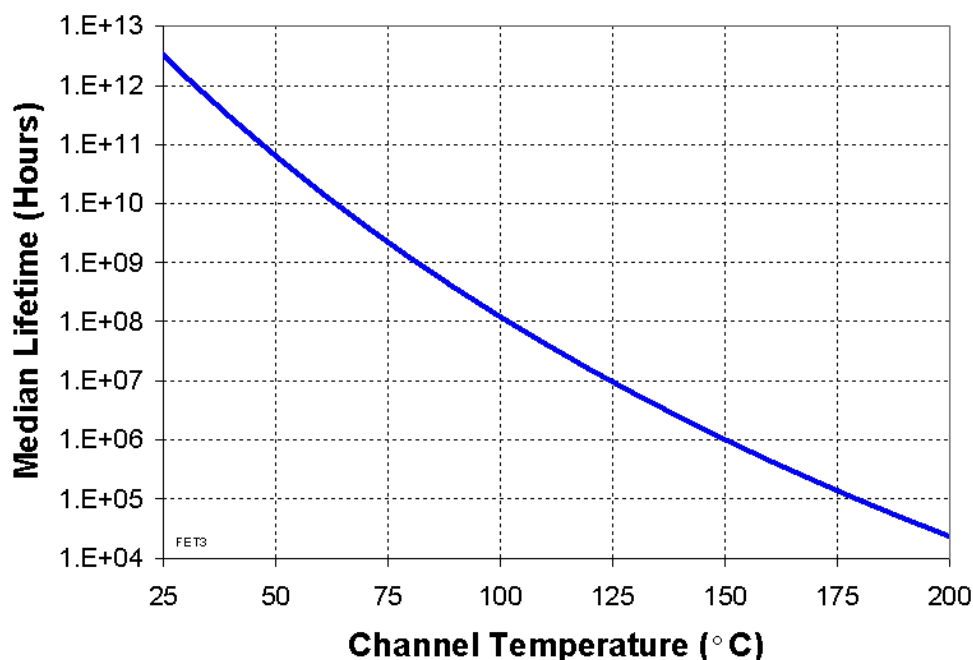
**Table IV**  
**Power Dissipation and Thermal Properties**

| Parameter                         | Test Conditions                    | Value  | Notes |
|-----------------------------------|------------------------------------|--|-------|
| Maximum Input Power               |                                    | Pin = 250 mW<br>Tchannel = 150 °C<br>Tm = 1.0E+6 Hrs               | 1/ 2/ |
| Thermal Resistance, $\theta_{jc}$ | Pin = 100 mW<br>Tbaseplate = 70 °C | $\theta_{jc}$ = 42 (°C/W)<br>Tchannel = 74.2 °C<br>Tm = 2.4E+9 Hrs |       |
| Mounting Temperature              | 30 seconds                         | 260 °C Max   |       |
| Storage Temperature               |                                    | -65 to 150 °C  |       |

- 1/ For a median life of 1E+6 hours, Input Power is limited to  

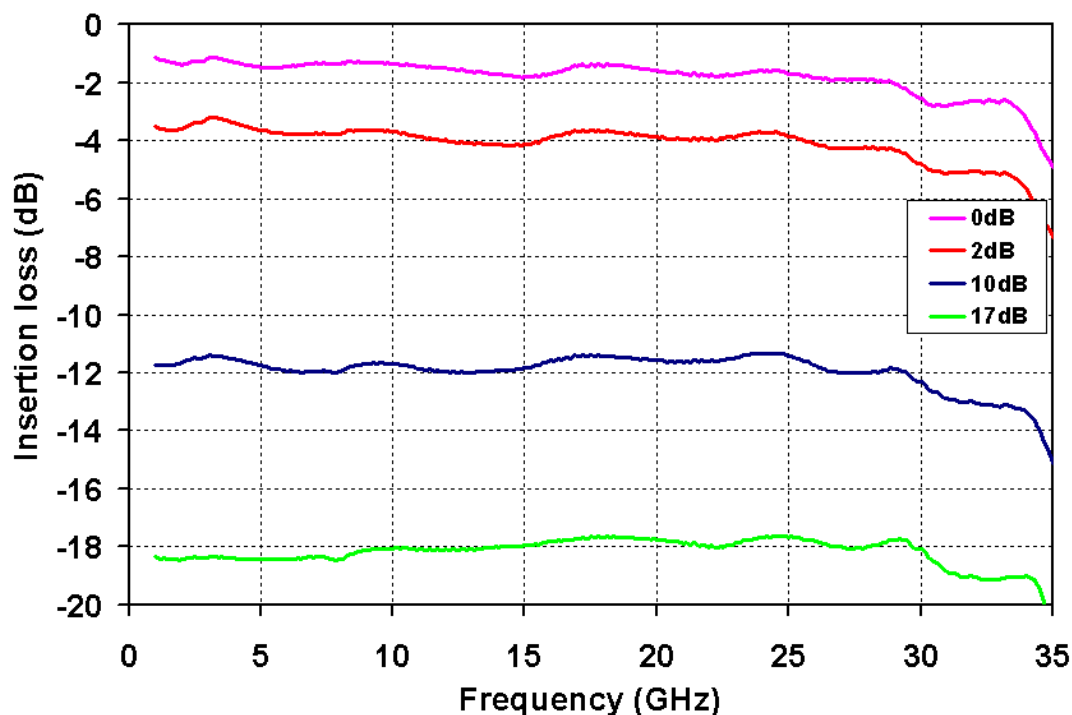
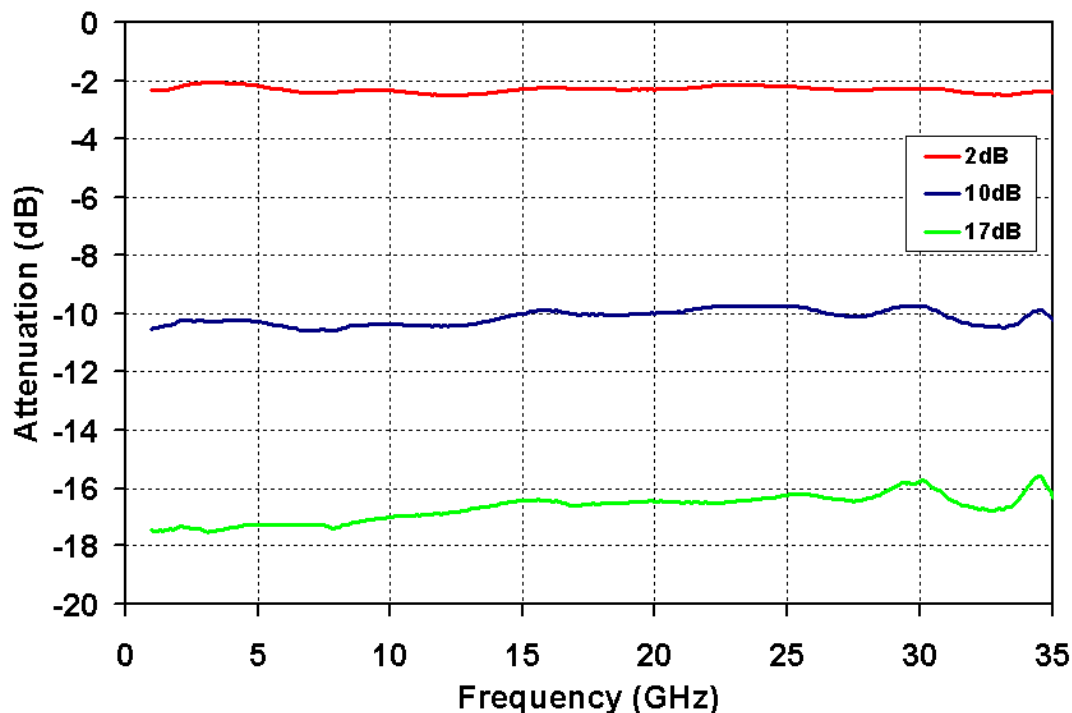
$$P_{in} = (150\text{ °C} - T_{base}\text{ °C})/\theta_{jc}.$$
- 2/ Channel operating temperature will directly affect the device median time (Tm). For maximum life, it is recommended that channel temperatures be maintained at the lowest possible levels.

### Median Lifetime (Tm) vs. Channel Temperature



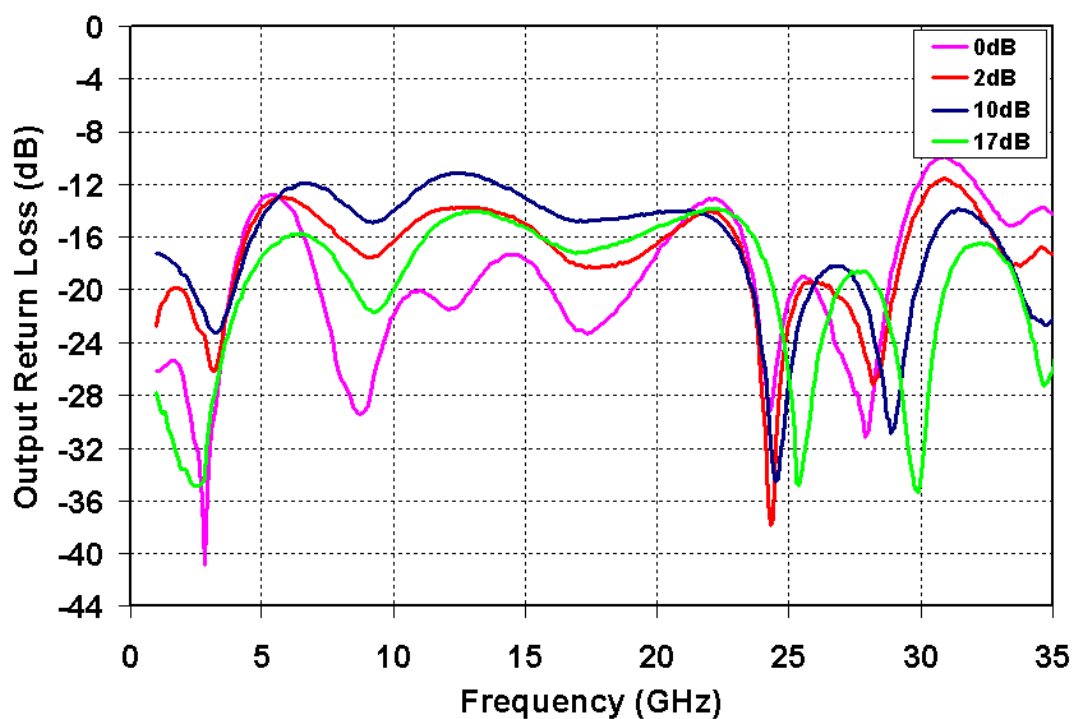
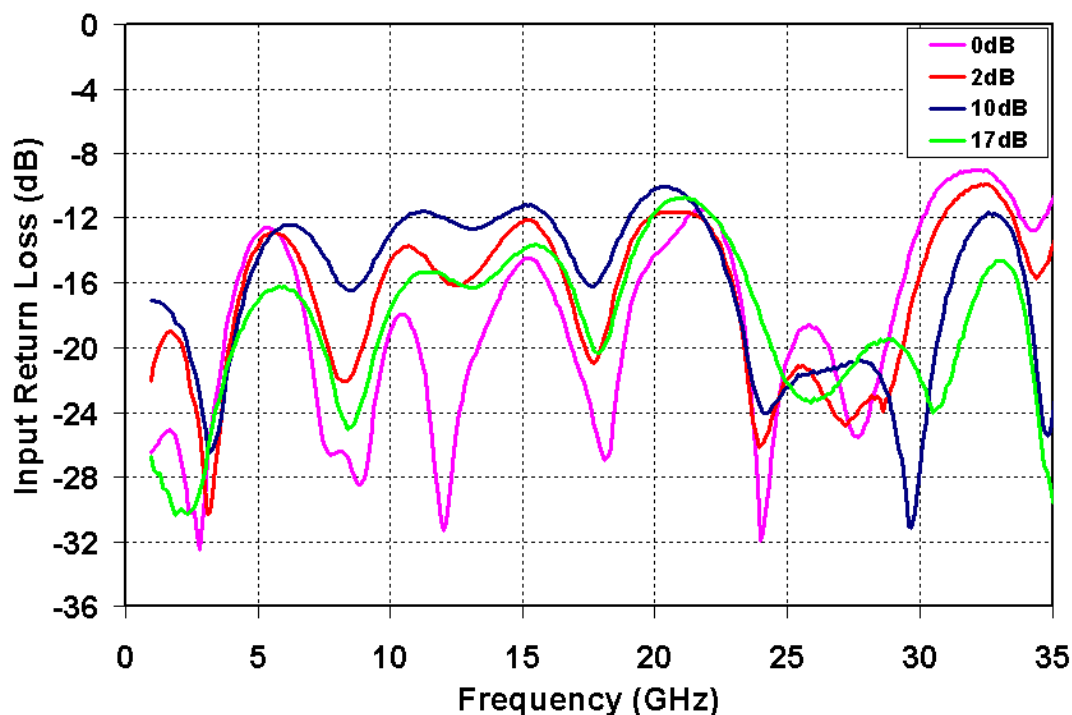
## Measured Data

See Table II for Recommended Bias V1 & V2, ( $T_A = 25^\circ\text{C}$  Nominal)



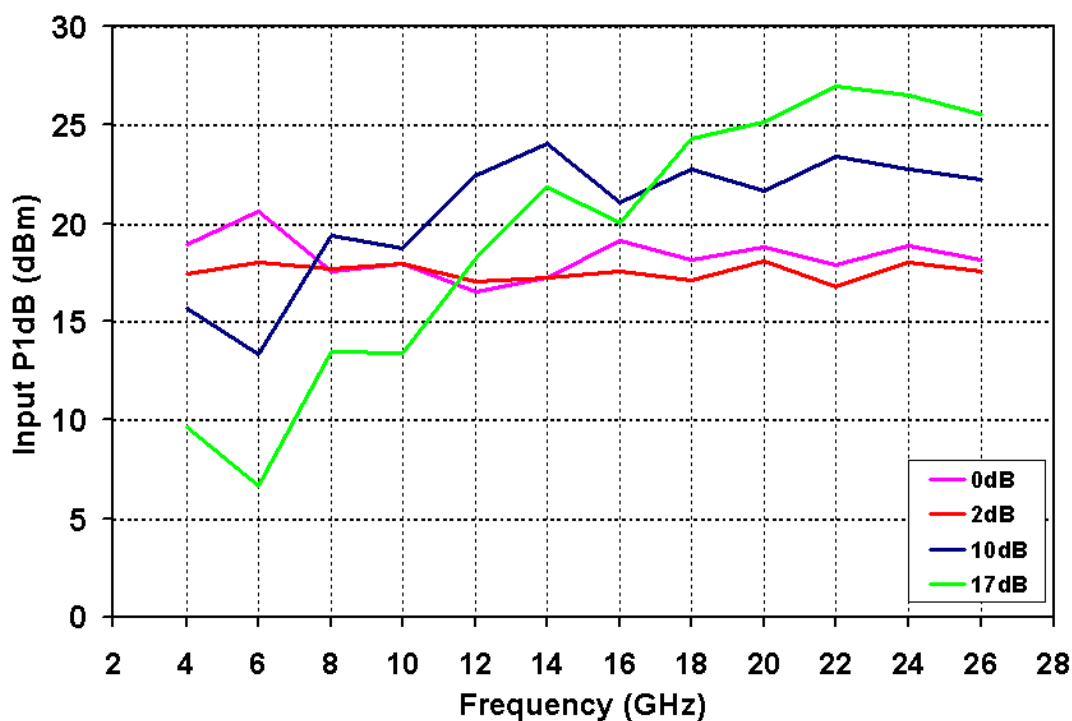
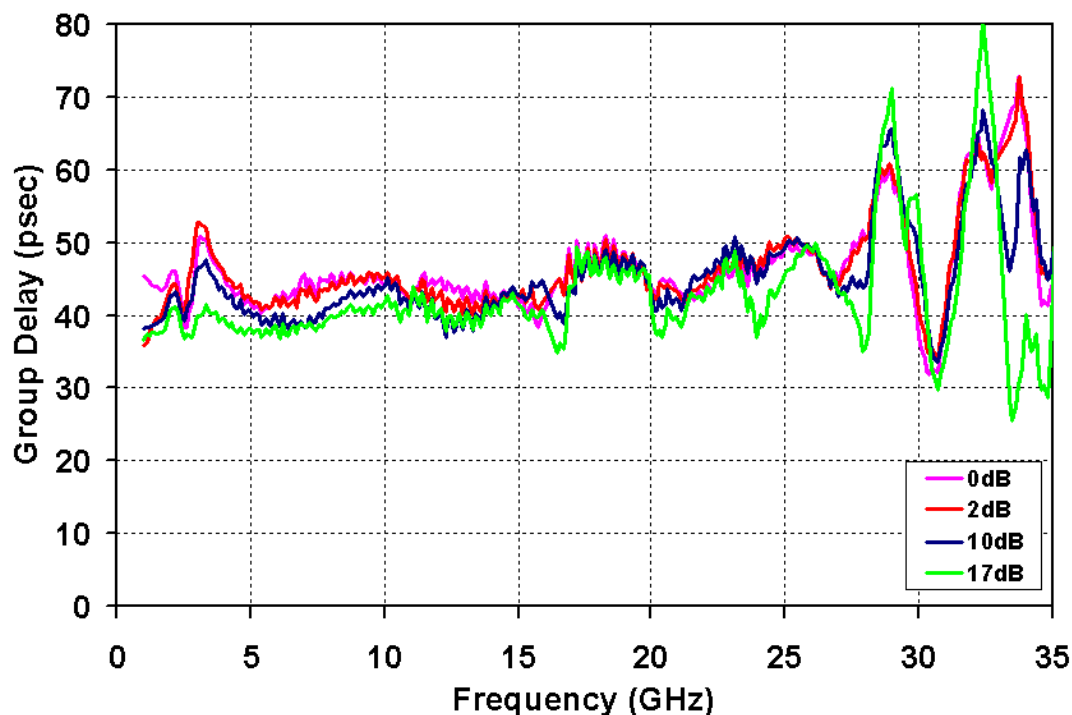
## Measured Data

See Table II for Recommended Bias V1 & V2 , ( $T_A = 25^\circ\text{C}$  Nominal)



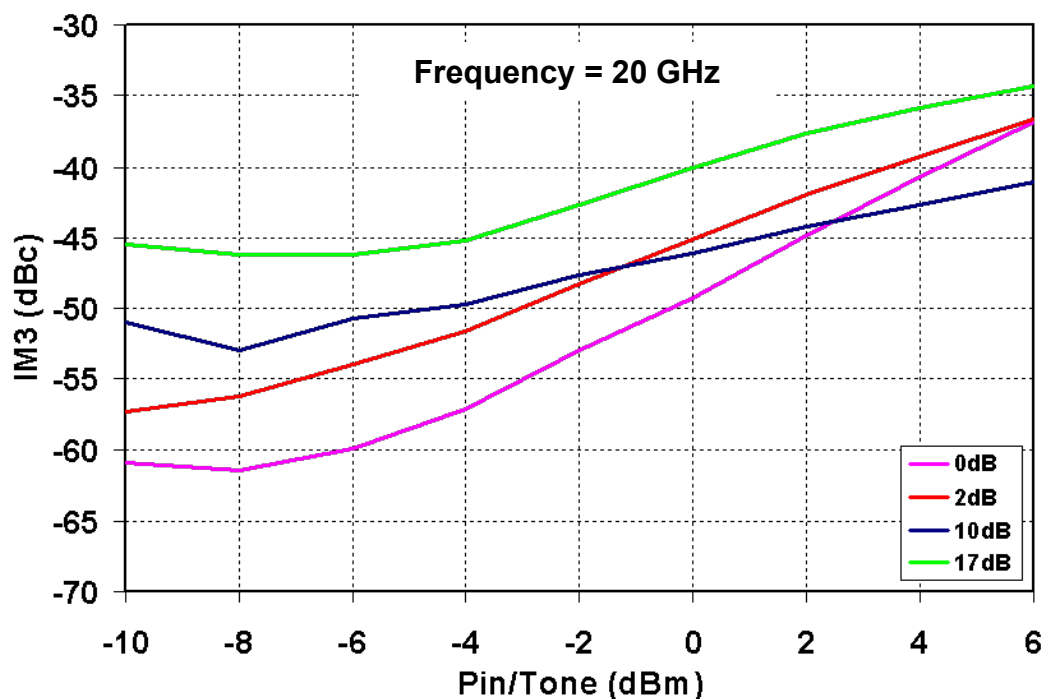
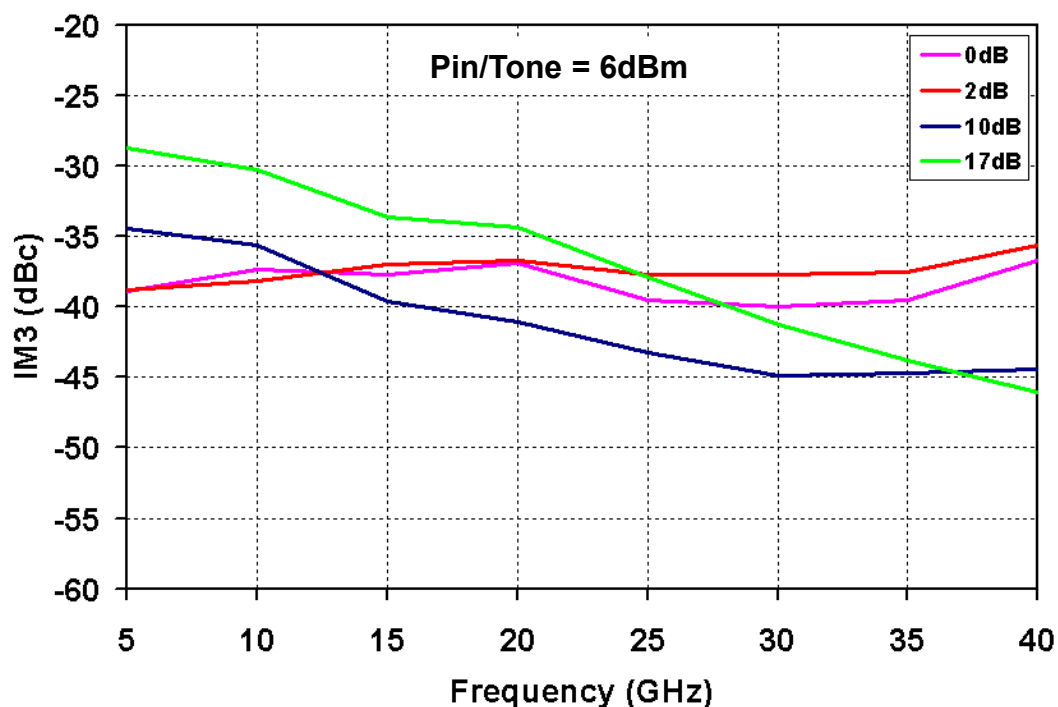
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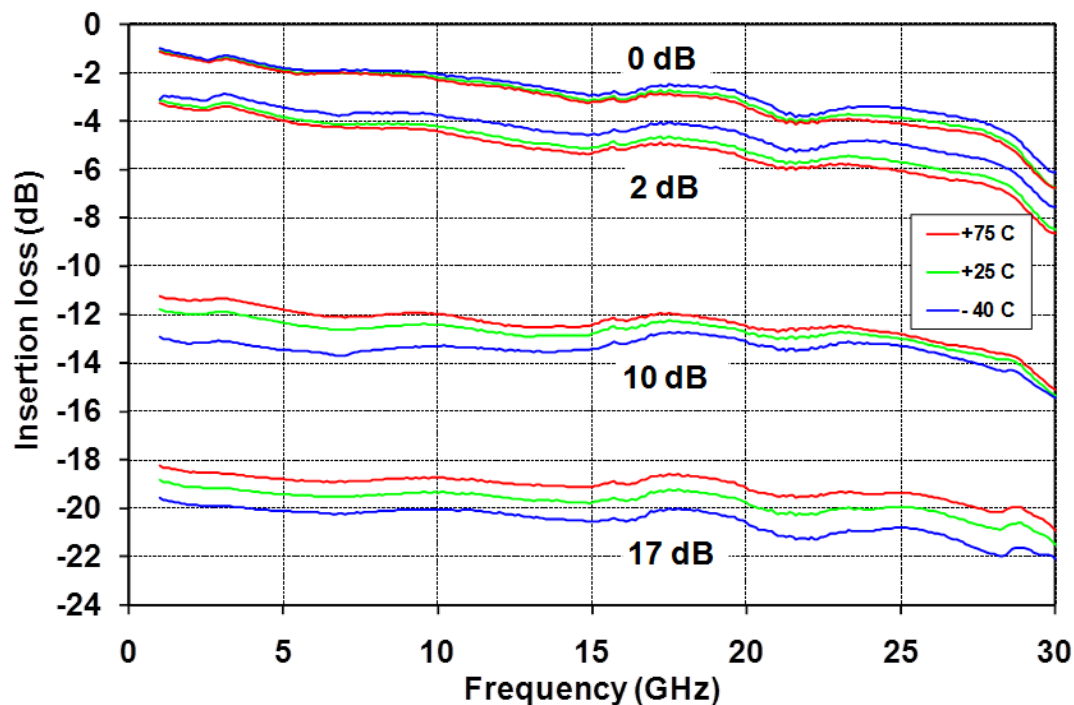
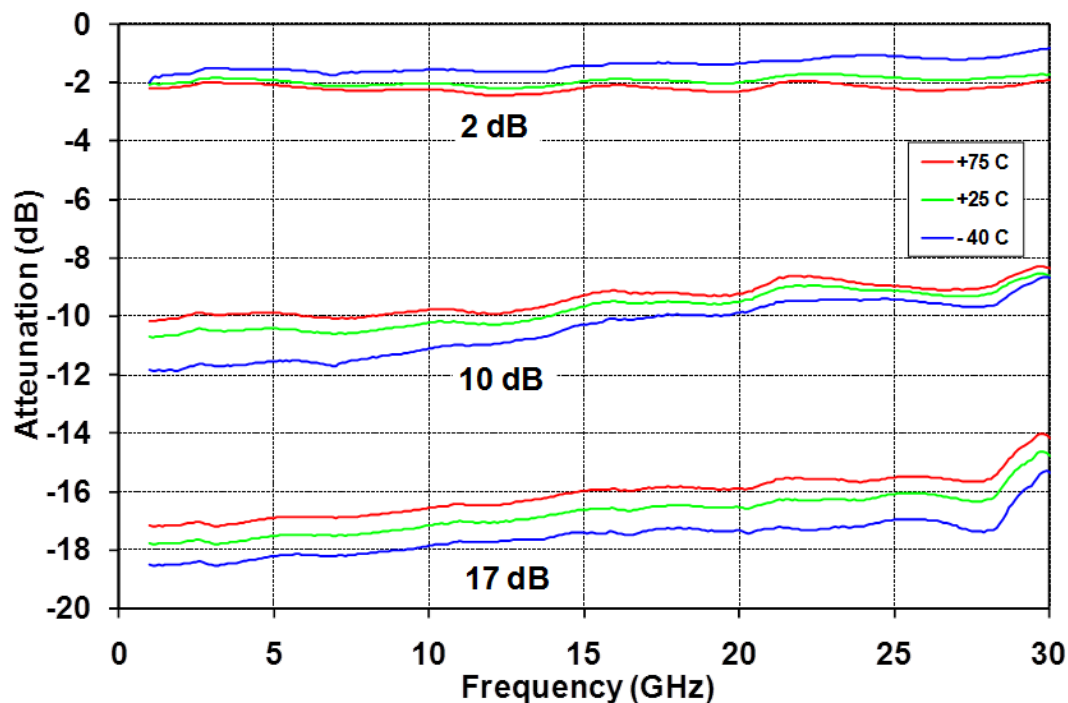




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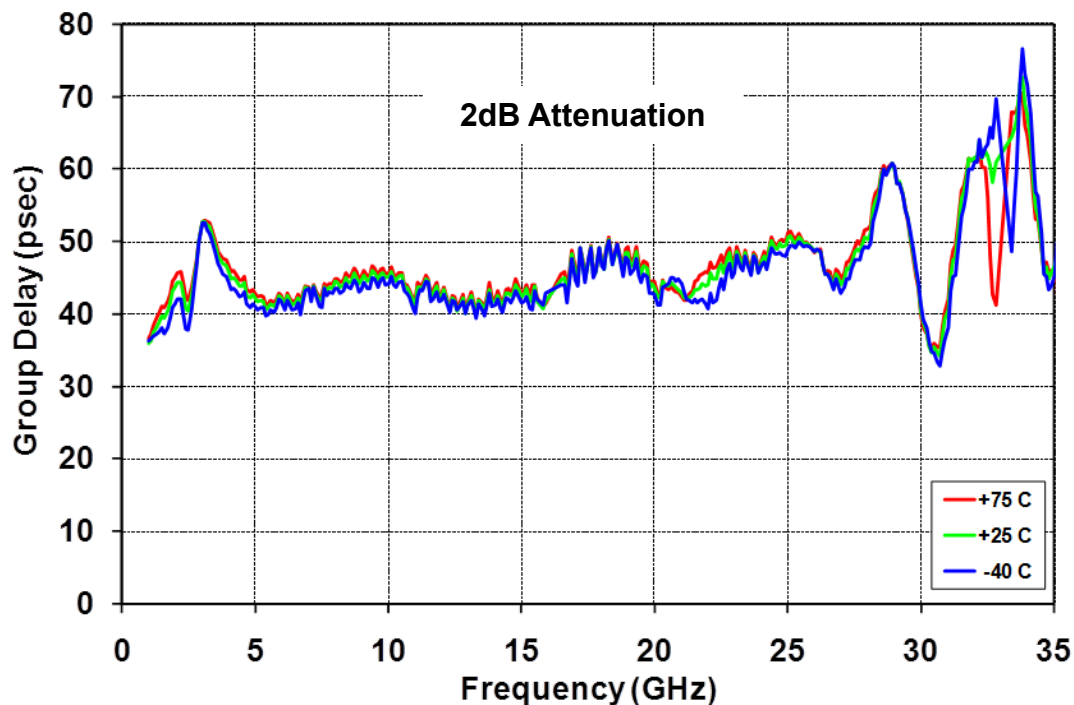
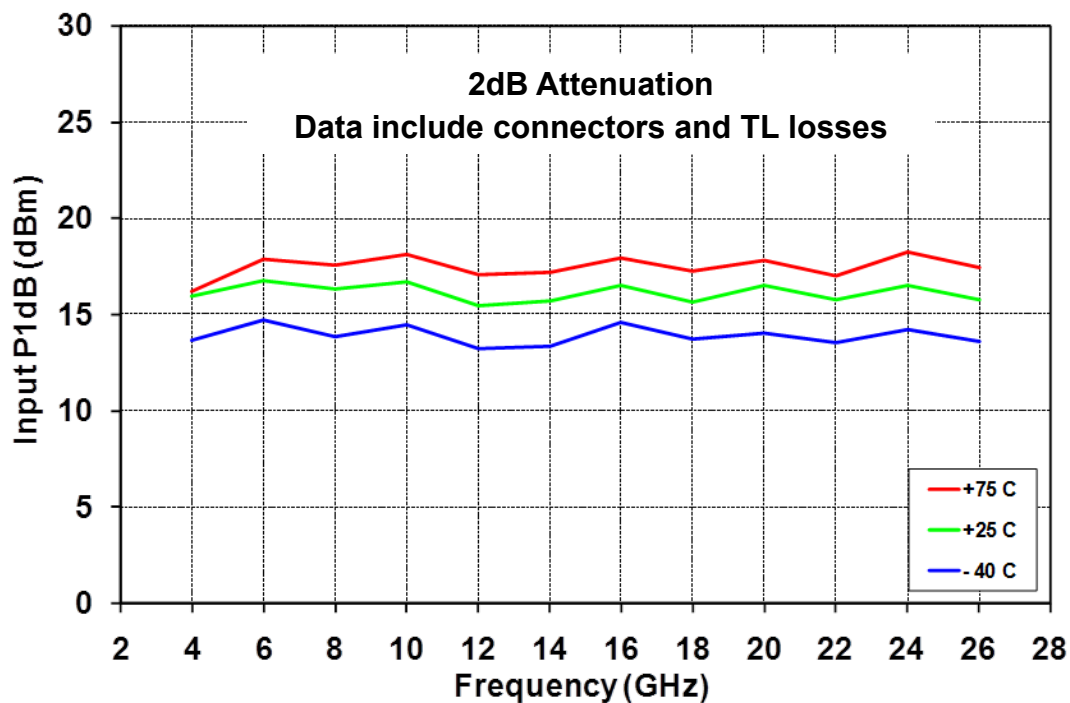
See Table II for Recommended Bias V1 & V2

Data include connectors and TL losses

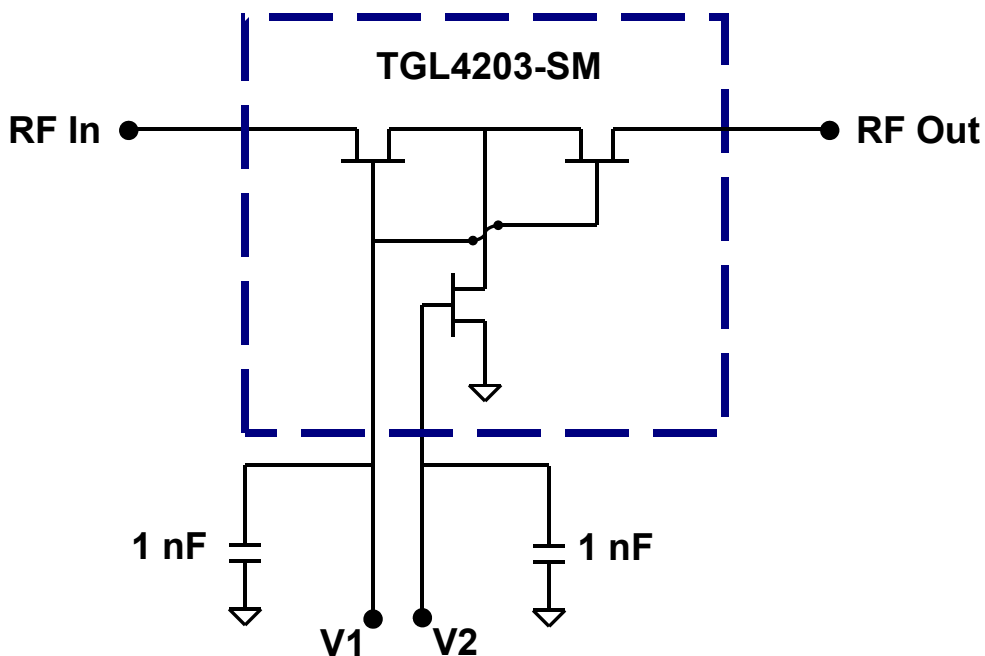


## Measured Data

See Table II for Recommended Bias V1 & V2



## Electrical Schematic



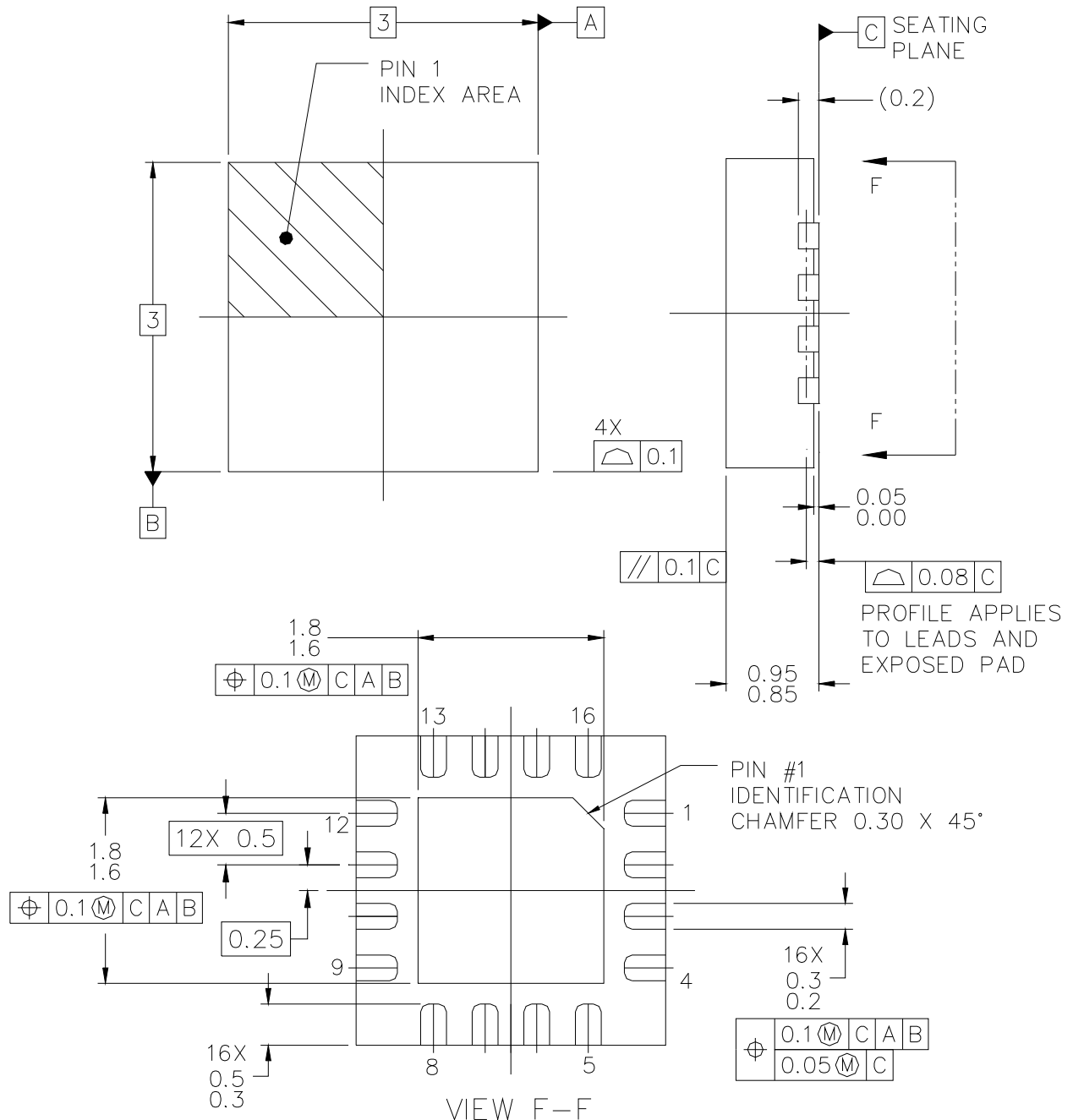
## Bias Procedures

### Bias-up Procedure

- V1 & V2 set to 0V
- Adjust V1 & V2 more negative according to Table II
- Apply RF (max. input level +24dBm)

### Bias-down Procedure

- Turn off RF
- Set V1 & V2 to 0V



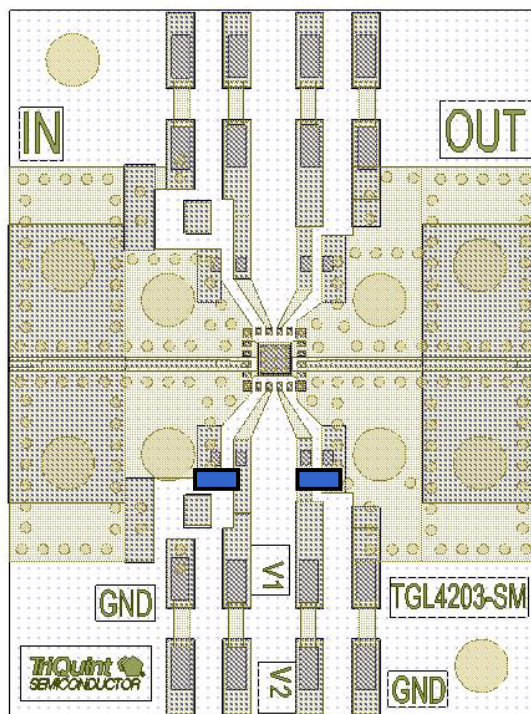
**RF In & RF Out can be reversed**

| Pin                  | Description |
|----------------------|-------------|
| 1, 2, 4, 9, 11, 12   | GND         |
| 3                    | RF In       |
| 5, 8, 13, 14, 15, 16 | N/C         |

| Pin | Description |
|-----|-------------|
| 6   | V1          |
| 7   | V2          |
| 10  | RF Out      |

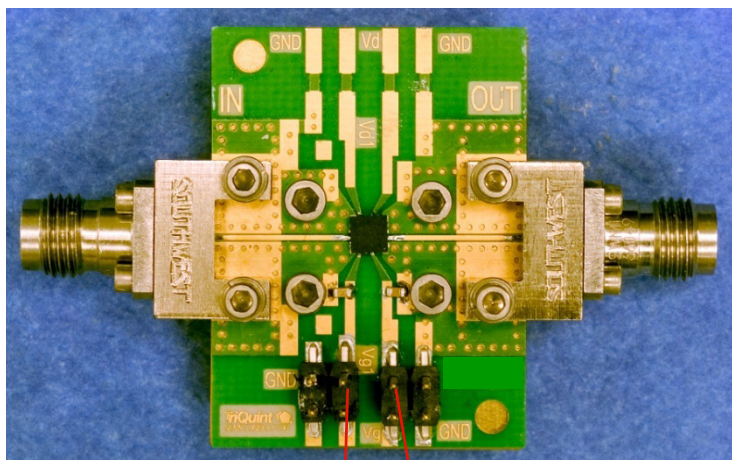
**GaAs MMIC devices are susceptible to damage from Electrostatic Discharge. Proper precautions should be observed during handling, assembly and test.**

## Recommended Evaluation Board



■ 1nF(size 0402) capacitors for DC decoupling

Board material is 8 mil ROGERS RO4003



V1

V2

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## Assembly Notes

### Recommended Surface Mount Package Assembly

- Proper ESD precautions must be followed while handling packages.
- Clean the board with acetone. Rinse with alcohol. Allow the circuit to fully dry.
- TriQuint recommends using a conductive solder paste for attachment. Follow solder paste and reflow oven vendors' recommendations when developing a solder reflow profile. Typical solder reflow profiles are listed in the table below.
- Hand soldering is not recommended. Solder paste can be applied using a stencil printer or dot placement. The volume of solder paste depends on PCB and component layout and should be well controlled to ensure consistent mechanical and electrical performance.
- Clean the assembly with alcohol.

## Typical Solder Reflow Profiles

| Reflow Profile                       | SnPb                        | Pb Free                     |
|--------------------------------------|-----------------------------|-----------------------------|
| Ramp-up Rate                         | 3 °C/sec                    | 3 °C/sec                    |
| Activation Time and Temperature      | 60 – 120 sec @ 140 – 160 °C | 60 – 180 sec @ 150 – 200 °C |
| Time above Melting Point             | 60 – 150 sec                | 60 – 150 sec                |
| Max Peak Temperature                 | 240 °C                      | 260 °C                      |
| Time within 5 °C of Peak Temperature | 10 – 20 sec                 | 10 – 20 sec                 |
| Ramp-down Rate                       | 4 – 6 °C/sec                | 4 – 6 °C/sec                |

## Ordering Information

| Part       | Package Style |
|------------|---------------|
| TGL4203-SM | 3X3 QFN       |

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